



## Absolute Maximum Ratings(Note 1)

Supply Voltage (V <sub>CC</sub> )	0.0V to +7.0V
Input Voltage (V <sub>I</sub> ) $V_I \le V_{CC}$	0.0V to +7.0V
DC Output Current (I <sub>OUT</sub> )	
Continuous	50 mA
Surge	100 mA
Storage Temperature (T <sub>STG</sub> )	$-65^{\circ}C$ to $+150^{\circ}C$

# Recommended Operating Conditions

Power Supply Operating	$V_{CC} = 3.0V$ to $3.8V$
LVTTL/LVCMOS Input Voltage	0.0V to V <sub>CC</sub>
Free Air Operating Temperature (T <sub>A</sub> )	-40°C to +85°C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum rating. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

# LVPECL DC Electrical Characteristics $V_{CC} = 3.3V$ ; GND = 0.0V (Note 2)

Symbol	Parameter	_40°C			25°C			85°C			Units
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Units
I <sub>CC</sub>	Power Supply Current			28			28			29	mA
V <sub>OH</sub>	Output HIGH Voltage (Note 3)	2215		2420	2275		2420	2275		2420	mV
V <sub>OL</sub>	Output LOW Voltage (Note 3)	1470		1745	1490		1680	1490		1680	mV

Note 2: Output parameters vary 1 to 1 with V\_CC. V\_CC can vary  $\pm 0.15 V.$ 

Note 3: Outputs are terminated through a  $50\Omega$  resistor to  $V_{CC}$  – 2.0V.

Note: Devices are designed to meet the DC specifications after thermal equilibrium has been established. Circuit is tested with air flow greater than 500LFPM maintained.

### LVTTL/LVCMOS DC Electrical Characteristics $V_{CC} = 3.3V$ ; GND = 0.0V (Note 4)

Symbol	Parameter	Min	Тур	Marri	Units	Condition
lu i			. , P	Max		
чн	Input HIGH Current			20		V <sub>IN</sub> = 2.7V
				100	μA	$V_{IN} = V_{CC}$
IIL	Input LOW Current			-200	μA	$V_{IN} = 0.5V$
V <sub>IK</sub>	Clamp Diode Voltage			-1.2	V	I <sub>IN</sub> = -18 mA
V <sub>IH</sub>	Input HIGH Voltage	2.0			V	
V <sub>IL</sub>	Input LOW Voltage			0.8	V	

Note 4:  $V_{CC}$  can vary ±0.15V.

Note: Devices are designed to meet the DC specifications after thermal equilibrium has been established. Circuit is tested with air flow greater than 500LFPM maintained.

#### AC Electrical Characteristics $V_{CC} = 3.3V$ ; GND = 0.0V (Note 5)

Symbol	Parameter	<b>−40°C</b>		25°C			85°C			Units	Figure	
Oymbol	i alameter	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max		Number
f <sub>MAX</sub>	Maximum Toggle Frequency		TBD			TBD			TBD		MHz	
t <sub>JITTER</sub>	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps	
t <sub>PLH</sub> / t <sub>PHL</sub>	Propagation Delay (Note 6)	200	350	600	200	350	600	200	350	600	ps	Figure 1
t <sub>SKEW</sub>	Skew Output-to-Output		30	100		30	100		30	100	DS	
	Part-to-Part			400			400			400	ps	
t <sub>r</sub> , t <sub>f</sub>	Output Rise Time Q (20% to 80%)	200		550	200		500	200		500	ns	Figure 2

Note 5:  $V_{CC}$  can vary ±0.15V.

Note 6: Specifications for standard LVTTL input signal (see Figure 1).







